





SN54AHCT574, SN74AHCT574 SCLS245N - OCTOBER 1995 - REVISED JULY 2024

## SNx4AHCT574 Octal Transparent D-Type Latches With 3-State Outputs

### **1** Features

Texas

INSTRUMENTS

- Inputs are TTL-voltage compatible
- Latch-up performance exceeds 250mA per JESD 17
- On products compliant to MIL-PRF-38535, all parameters are tested unless otherwise noted. On all other products, production processing does not necessarily include testing of all parameters.
- ESD protection exceeds JESD 22
  - 2000V human-body model (A114-A) \_
    - 1000V charged-device model (C101)

### 2 Applications

- **Smartphone Handsets** •
- PDAs
- **Network Switches**
- Wearable Health and Fitness Devices
- Televisions (LCDs)
- Power Infrastructures

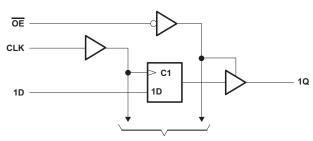
### **3 Description**

The SNx4AHCT574 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads.

Device	Information
Device	mormation

PART NUMBER	PACKAGE <sup>(1)</sup>	PACKAGE SIZE <sup>(2)</sup>	BODY SIZE <sup>(3)</sup>							
	DB (SSOP, 20)	7.2mm × 7.8mm	7.50mm x 5.30mm							
	DGV (TVSOP, 20)	5.00mm x 6.4mm	5.00mm x 4.40mm							
SNx4AHCT574	DW (SOIC, 20)	12.80mm × 10.3mm	12.8mm x 7.5mm							
	N (PDIP, 20)	24.33mm x 9.4mm	25.40mm x 6.35mm							
	PW (TSSOP, 20)	6.50mm × 6.4mm	6.50mm x 4.40mm							

- (1) For more information, see Section 11.
- The package size (length × width) is a nominal value and (2)includes pins, where applicable.
- (3) The body size (length × width) is a nominal value and does not include pins.



To Seven Other Channels **Simplified Schematic** 





## **Table of Contents**

1 Features1	
2 Applications1	
3 Description1	
4 Pin Configuration and Functions	;
5 Specifications4	
5.1 Absolute Maximum Ratings4	
5.2 ESD Ratings4	
5.3 Recommended Operating Conditions4	
5.4 Thermal Information5	
5.5 Electrical Characteristics5	
5.6 Timing Requirements5	
5.7 Switching Characteristics6	i.
5.8 Operating Characteristics6	j.
5.9 Typical Characteristics6	i.
6 Parameter Measurement Information7	
7 Detailed Description8	1
7.1 Overview	
7.2 Functional Block Diagram8	

7.3 Feature Description	8
7.4 Device Functional Modes	
8 Application and Implementation	9
8.1 Application Information	
8.2 Typical Application	9
8.3 Power Supply Recommendations	
8.4 Layout	10
9 Device and Documentation Support	
9.1 Receiving Notification of Documentation Updates.	11
9.2 Support Resources	11
9.3 Related Links	11
9.4 Trademarks	11
9.5 Electrostatic Discharge Caution	11
9.6 Glossary	
10 Revision History	11
11 Mechanical, Packaging, and Orderable	
Information	12

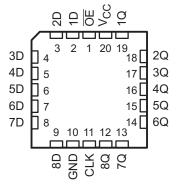


### **4 Pin Configuration and Functions**

SN54AHCT574 . . . J OR W PACKAGE SN74AHCT574 . . . DB, DGV, DW, N, NS, OR PW PACKAGE (TOP VIEW)

	•	
OE	1	
1D	2	19 ] 1Q
2D	3	18 ] 2Q
3D	4	17 🛛 3Q
4D	5	16 ] 4Q
5D	6	15 <b>]</b> 5Q
6D	7	14 🛛 6Q
7D	8	13 ] 7Q
8D	9	12 🛛 8Q
GND	10	11 CLK

#### SN54AHCT574 . . . FK PACKAGE (TOP VIEW)



#### Table 4-1. Pin Functions

PIN		I/O	DESCRIPTION					
NO.	NAME	1/0						
1	OE	I	Output Enable					
2	1D	I	1D Input					
3	2D	I	2D Input					
4	3D	I	3D Input					
5	4D	I	4D Input					
6	5D	I	5D Input					
7	6D	I	6D Input					
8	7D	I	7D Input					
9	8D	I	8D Input					
10	GND		Ground Pin					
11	CLK	I	Clock Pin					
12	8Q	0	8Q Output					
13	7Q	0	7Q Output					
14	6Q	0	6Q Output					
15	5Q	0	5Q Output					
16	4Q	0	4Q Output					
17	3Q	0	3Q Output					
18	2Q	0	2Q Output					
19	1Q	0	1Q Output					
20	V <sub>CC</sub>		Power Pin					



### **5** Specifications

### 5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

			MIN	MAX	UNIT
V <sub>CC</sub>	Supply voltage range		-0.5	7	V
VI	Input voltage range <sup>(2)</sup>		-0.5	7	V
Vo	Output voltage range <sup>(2)</sup>		-0.5	V <sub>CC</sub> + 0.5	V
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-20	mA
I <sub>OK</sub>	Output clamp current	$V_{O} < 0 \text{ or } V_{O} > V_{CC}$		±20	mA
I <sub>O</sub>	Continuous output current	V <sub>O</sub> = 0 to V <sub>CC</sub>		±25	mA
	Continuous current through V <sub>CC</sub> or GND			±50	mA
T <sub>stg</sub>	Storage temperature range		-65	150	°C

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### 5.2 ESD Ratings

			Value	UNIT
		Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins <sup>(1)</sup>	±2000	
V <sub>(ESD)</sub>	Electrostatic discharge	Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup>	±1000	V

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

### **5.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		SN54AH	SN54AHCT574		SN74AHCT574		
		MIN	MAX	MIN	MAX	UNIT	
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	V	
V <sub>IH</sub>	High-level input voltage	2		2		V	
VIL	Low-level input voltage		0.8		0.8	V	
VI	Input voltage	0	5.5	0	5.5	V	
Vo	Output voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V	
I <sub>ОН</sub>	High-level output current		-8		-8	mA	
I <sub>OL</sub>	Low-level output current		8		8	mA	
Δt/Δv	Input transition rise or fall rate		20		20	ns/V	
T <sub>A</sub>	Operating free-air temperature	-55	125	-40	125	°C	

 All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs (SCBA004).



### **5.4 Thermal Information**

		SN74AHCT574						
	THERMAL METRIC <sup>(1)</sup>	DW (SOIC)	DB (SSOP)	DGV (TVSOP)	N (PDIP)	NS (SOP)	PW (TSSOP)	UNIT
		20 PINS						
R <sub>0JA</sub>	Junction-to-ambient thermal resistance	81.1	97.9	117.2	53.3	79.2	116.8	
R <sub>0JC(top)</sub>	Junction-to-case (top) thermal resistance	48.9	59.6	32.7	40.0	45.7	58.5	
R <sub>θJB</sub>	Junction-to-board thermal resistance	53.8	53.1	58.7	34.2	46.8	78.7	°C/W
ΨJT	Junction-to-top characterization parameter	19.5	21.3	1.15	26.4	19.3	12.6	C/VV
Ψ <sub>JB</sub>	Junction-to-board characterization parameter	53.1	52.7	58.0	34.1	46.4	77.9	
R <sub>0JC(bot)</sub>	Junction-to-case (bottom) thermal resistance	N/A	N/A	N/A	N/A	N/A	N/A	

(1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report (SPRA953).

### **5.5 Electrical Characteristics**

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	V <sub>cc</sub>	T <sub>A</sub> = 25°C			SN54AHCT574		-40°C to 85°C SN74AHCT574		-40°C to 125°C SN74AHCT574		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
V <sub>OH</sub>	I <sub>OH</sub> = −50 μA	4.5 V	4.4	4.5		4.4		4.4		4.4		V
⊻он	I <sub>OH</sub> = −8 mA	4.5 V	3.94			3.8		3.8		3.8		v
N	I <sub>OL</sub> = 50 μA	4.5 V			0.1		0.1		0.1		0.1	V
V <sub>OL</sub>	I <sub>OL</sub> = 8 mA	4.5 V			0.36		0.44		0.44		0.44	v
lı lı	V <sub>I</sub> = 5.5 V or GND	0 V to 5.5 V			±0.1		±1 <sup>(1)</sup>		±1		±1	μA
I <sub>OZ</sub>	V <sub>O</sub> = V <sub>CC</sub> or GND	5.5 V			±0.25		±2.5		±2.5		±2.5	μA
I <sub>CC</sub>	$V_{I} = V_{CC}$ or GND, $I_{O} = 0$	5.5 V			4		40		40		40	μA
ΔI <sub>CC</sub> <sup>(2)</sup>	One input at 3.4 V, Other inputs at $V_{CC}$ or GND	5.5 V			1.35		1.5		1.5		1.5	mA
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		3	10				10			pF
Co	V <sub>O</sub> = V <sub>CC</sub> or GND	5 V		3								pF

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested at  $V_{CC} = 0 V$ .

(2) This is the increase in supply current for each input at one of the specified TTL voltage levels, rather than 0 V or V<sub>CC</sub>.

### **5.6 Timing Requirements**

over recommended operating free-air temperature range,  $V_{CC} = 5 V \pm 0.5 V$  (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

		T <sub>A</sub> = 25°C		SN54AHCT574		SN74AH0	CT574	T <sub>A</sub> = -40°C to 125°C SN74AHCT574		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
tw	Pulse duration, LE high	5.5		5.5		5.5		5.5		ns
t <sub>su</sub>	Setup time, data before LE $\downarrow$	3.5		3.5		3.5		3.5		ns
t <sub>h</sub>	Hold time, data after LE $\downarrow$	1.5		1.5		1.5		1.5		ns



### **5.7 Switching Characteristics**

over recommended operating free-air temperature range,  $V_{CC}$  = 5 V ± 0.5 V (unless otherwise noted) (see Load Circuit and Voltage Waveforms)

PARAMETER	FROM (OUTPUT)	TO (INPUT)	LOAD CAPACITANCE	T <sub>A</sub> = 25°C		SN54AHCT574		SN74AHCT574		T <sub>A</sub> = -40°C to 125°C SN74AHCT574		UNIT											
	(001701)	(INPOT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	MIN	MAX											
£			C <sub>L</sub> = 15 pF	130 <sup>(1)</sup>	180 <mark>(1)</mark>		110 <sup>(1)</sup>		110		110		ns										
f <sub>max</sub>		C <sub>L</sub> = 50 pF	85	115		75		75		75		115											
t <sub>PLH</sub>	CLK	0	C <sub>1</sub> = 15 pF		5.5 <sup>(1)</sup>	8.6 <sup>(1)</sup>	1 <sup>(1)</sup>	10 <sup>(1)</sup>	1	10	1	11	20										
t <sub>PHL</sub>	ULK	Q	Q	Q	Q	Q	Q	Q	C <sub>L</sub> = 15 pr		5.5 <sup>(1)</sup>	8.6 <sup>(1)</sup>	1(1)	10 <sup>(1)</sup>	1	10	1	11	ns				
t <sub>PZH</sub>	ŌĒ	0	0 - 15 - 5		5 <sup>(1)</sup>	9 <mark>(1)</mark>	1(1)	10.5 <mark>(1)</mark>	1	10.5	1	11.5	ns										
t <sub>PZL</sub>	UE	Ē Q	Q	Q	C <sub>L</sub> = 15 pF		5 <sup>(1)</sup>	9 <mark>(1)</mark>	1(1)	10.5 <mark>(1)</mark>	1	10.5	1	11.5	ns								
t <sub>PHZ</sub>	OE	Q	C <sub>1</sub> = 15 pF		5.5 <sup>(1)</sup>	9 <mark>(1)</mark>	1(1)	10.5 <mark>(1)</mark>	1	10.5	1	11.5	ns										
t <sub>PLZ</sub>		Q	GL = 15 pF		5.5 <sup>(1)</sup>	9 <sup>(1)</sup>	1 <sup>(1)</sup>	10.5 <sup>(1)</sup>	1	10.5	1	11.5											
t <sub>PLH</sub>	CLK	0	0	Q	C <sub>1</sub> = 50 pF		7	10.6	1	12	1	12	1	13									
t <sub>PHL</sub>	ULK	Q	C <sub>L</sub> = 50 pF		7	10.6	1	12	1	12	1	13	ns										
t <sub>PZH</sub>	- <del>DE</del> Q	0	0	0	0		0	0	0	C <sub>1</sub> = 50 pF		6	11	1	12.5	1	12.5	1	13.5	ns			
t <sub>PZL</sub>		Q	C <sub>L</sub> = 50 pr		6	11	1	12.5	1	12.5	1	13.5											
t <sub>PHZ</sub>	OE Q				0	0	0	Q	0	0	0	0	C <sub>1</sub> = 50 pF		7	10.1	1	11.5	1	11.5	1	13	ns
t <sub>PLZ</sub>		Q	CL = 50 PF		7	10.1	1	11.5	1	11.5	1	13	115										
t <sub>sk(o)</sub>			C <sub>L</sub> = 50 pF			1 <sup>(2)</sup>				1			ns										

(1) On products compliant to MIL-PRF-38535, this parameter is not production tested.

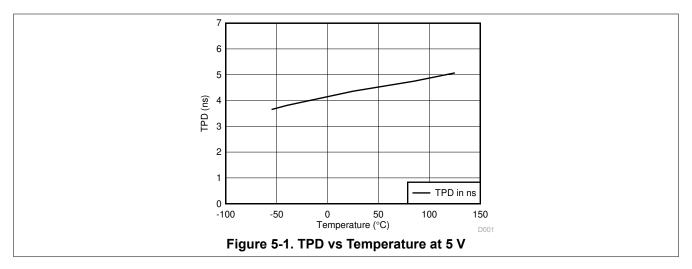
(2) On products compliant to MIL-PRF-38535, this parameter does not apply.

### **5.8 Operating Characteristics**

 $V_{CC} = 5 V, T_A = 25^{\circ}C$ 

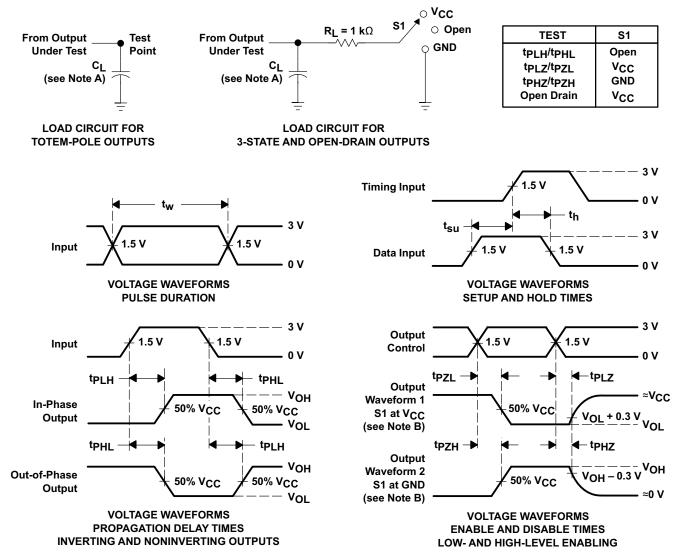
	PARAMETER	TEST CC	ТҮР	UNIT	
C <sub>pd</sub>	Power dissipation capacitance	No load,	f = 1 MHz	28	pF

### **5.9 Typical Characteristics**





### **6** Parameter Measurement Information



NOTES: A. Cl includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  1 MHz, Z<sub>O</sub> = 50  $\Omega$ , t<sub>r</sub>  $\leq$  3 ns, t<sub>f</sub>  $\leq$  3 ns.
- D. The outputs are measured one at a time with one input transition per measurement.
- E. All parameters and waveforms are not applicable to all devices.

#### Figure 6-1. Load Circuit and Voltage Waveforms



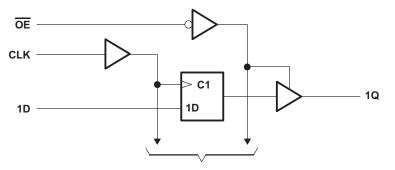
### 7 Detailed Description

### 7.1 Overview

The SNx4AHCT574 devices are octal edge-triggered D-type flip-flops that feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. These devices are particularly suitable for implementing buffer registers, IO ports, bidirectional bus drivers, and working registers.

Regarding the positive transition of the clock (CLK) input, the Q outputs are set to the logic levels of the data (D) inputs. A buffered output-enable ( $\overline{OE}$ ) input places the eight outputs in either a normal logic state (high or low) or the high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without interface or pull-up components.

### 7.2 Functional Block Diagram



To Seven Other Channels

### 7.3 Feature Description

- TTL inputs
  - Lowered switching threshold allows up translation 3.3 V to 5 V
- Slow edges reduce output ringing

### 7.4 Device Functional Modes

	(Each	Flip-	Flop)				
	INPUTS	OUTPUT					
ŌE	CLK	D	Q				
L	1	Н	Н				
L	Ť	L	L				
L	H or L	х	Q <sub>0</sub>				
н	Х	Х	Z				

# Table 7-1. Function Table



### 8 Application and Implementation

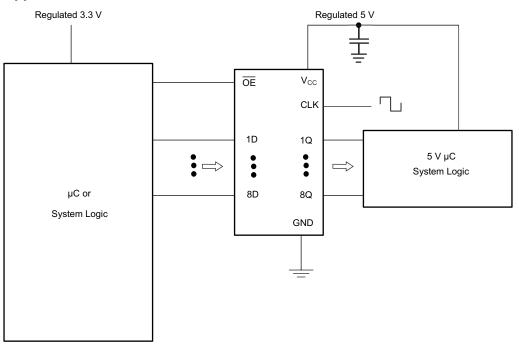
#### Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The SN74AHCT574 is a low-drive CMOS device that can be used for a multitude of bus interface type applications where output ringing is a concern. The low drive and slow edge rates will minimize overshoot and undershoot on the outputs. The input switching levels have been lowered to accommodate TTL inputs of 0.8-V  $V_{IL}$  and 2-V  $V_{IH}$ . This feature makes the device ideal for translating up from 3.3 V to 5 V. Figure 8-2 shows this type of translation.

#### 8.2 Typical Application





#### 8.2.1 Design Requirements

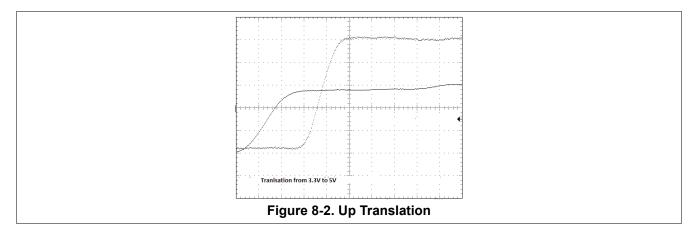
This device uses CMOS technology and has balanced output drive. Care should be taken to avoid bus contention because it can drive currents that would exceed maximum limits. The high drive will also create fast edges into light loads; therefore, routing and load conditions should be considered to prevent ringing.

#### 8.2.2 Detailed Design Procedure

- 1. Recommended input conditions
  - Rise time and fall time specs: See ( $\Delta t/\Delta V$ ) in the Section 5.3 table.
  - Specified High and low levels: See (V<sub>IH</sub> and V<sub>IL</sub>) in the Section 5.3 table.
  - Inputs are overvoltage tolerant allowing them to go as high as 5.5 V at any valid V<sub>CC</sub>.
- 2. Recommend output conditions
  - Load currents should not exceed 25 mA per output and 75 mA total for the part.
  - Outputs should not be pulled above V<sub>CC</sub>.



#### 8.2.3 Application Curves



### 8.3 Power Supply Recommendations

The power supply can be any voltage between the MIN and MAX supply voltage rating located in the Section 5.3 table.

Each V<sub>CC</sub> pin should have a good bypass capacitor to prevent power disturbance. For devices with a single supply, 0.1  $\mu$ F bypass capacitor is recommended. If there are multiple V<sub>CC</sub> pins, 0.01  $\mu$ F or 0.022  $\mu$ F is recommended for each power pin. It is acceptable to parallel multiple bypass capacitors to reject different frequencies of noise. A 0.1  $\mu$ F and 1  $\mu$ F are commonly used in parallel. The bypass capacitor should be installed as close to the power pin as possible for best results.

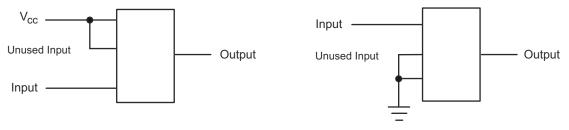
### 8.4 Layout

#### 8.4.1 Layout Guidelines

When using multiple bit logic devices inputs should not ever float.

In many cases, functions or parts of functions of digital logic devices are unused, for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such input pins should not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. Specified in Figure 8-3 are the rules that must be observed under all circumstances. All unused inputs of digital logic devices must be connected to a high or low bias to prevent them from floating. The logic level that should be applied to any particular unused input depends on the function of the device. Generally they will be tied to GND or  $V_{CC}$ ; whichever makes more sense or is more convenient. It is generally acceptable to float outputs unless the part is a transceiver. If the transceiver has an output enable pin, it will disable the outputs section of the part when asserted. This will not disable the input section of the IO's so they cannot float when disabled.

#### 8.4.2 Layout Example







### 9 Device and Documentation Support

#### 9.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

#### 9.2 Support Resources

TI E2E<sup>™</sup> support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

#### 9.3 Related Links

The table below lists quick access links. Categories include technical documents, support and community resources, tools and software, and quick access to sample or buy.

	Table 5-1. Related LITIRS												
PARTS	PRODUCT FOLDER	SAMPLE & BUY	TECHNICAL DOCUMENTS	TOOLS & SOFTWARE	SUPPORT & COMMUNITY								
SN54AHCT574	Click here	Click here	Click here	Click here	Click here								
SN74AHCT574	Click here	Click here	Click here	Click here	Click here								

#### Table 9-1. Related Links

### 9.4 Trademarks

TI E2E<sup>™</sup> is a trademark of Texas Instruments.

All trademarks are the property of their respective owners.

### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### 9.6 Glossary

TI Glossary This glossary lists and explains terms, acronyms, and definitions.

### **10 Revision History**

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

С	hanges from Revision M (September 2014) to Revision N (July 2024)	Page
•	Updated the numbering format for tables, figures, and cross-references throughout the document	1
•	Deleted machine model from <i>Features</i> section	1
•	Updated RθJA values: PW = 103.3 to 116.8, DW = 79.4 to 81.1; Updated PW and DW packages for	
	RθJC(top), RθJB, ΨJT, ΨJB, and RθJC(bot), all values in °C/W	5

Changes from Revision L (July 2003) to Revision M (September 2014)	
Updated document to new TI data sheet format	1
Deleted Ordering Information table	1
Added Military Disclaimer to Features list	
Added Pin Functions table	



•	Added Handling Ratings table	4
	Changed MAX operating temperature to 125°C in Recommended Operating Conditions table	
•	Added Thermal Information table	5
•	Added –40°C to 125°C for SN74AHCT574 in the Electrical Characteristics table	5
•	Added T <sub>A</sub> = -40°C to 125°C for SN74AHCT574 in the Timing Requirements table	5
•	Added T <sub>A</sub> = -40°C to 125°C for SN74AHCT574 in the Switching Characteristics table	6
•	Added Typical Characteristics	6
•	Added Application and Implementation section	9
	Added Power Supply Recommendations and Layout sections	

### 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

Copyright © 2024 Texas Instruments Incorporated



### PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
5962-9685301Q2A	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9685301Q2A SNJ54AHCT 574FK	Samples
5962-9685301QRA	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QR A SNJ54AHCT574J	Samples
5962-9685301QSA	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QS A SNJ54AHCT574W	Samples
SN74AHCT574DBR	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DBRE4	ACTIVE	SSOP	DB	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DGVR	ACTIVE	TVSOP	DGV	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574DW	OBSOLETE	SOIC	DW	20		TBD	Call TI	Call TI	-40 to 125	AHCT574	
SN74AHCT574DWR	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT574	Samples
SN74AHCT574N	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-40 to 125	SN74AHCT574N	Samples
SN74AHCT574NSR	ACTIVE	SO	NS	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	AHCT574	Samples
SN74AHCT574PW	OBSOLETE	TSSOP	PW	20		TBD	Call TI	Call TI	-40 to 125	HB574	
SN74AHCT574PWR	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SN74AHCT574PWRG4	ACTIVE	TSSOP	PW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-40 to 125	HB574	Samples
SNJ54AHCT574FK	ACTIVE	LCCC	FK	20	55	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962- 9685301Q2A SNJ54AHCT 574FK	Samples
SNJ54AHCT574J	ACTIVE	CDIP	J	20	20	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QR A SNJ54AHCT574J	Samples
SNJ54AHCT574W	ACTIVE	CFP	W	20	25	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-9685301QS A	Samples



Orderable Device	Status (1)	Package Type Package Drawing	ckage Qty	Eco Plan (2)	Lead finish/ Ball material	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
					(6)			SNJ54AHCT574W	

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

<sup>(5)</sup> Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

#### OTHER QUALIFIED VERSIONS OF SN54AHCT574, SN74AHCT574 :

Catalog : SN74AHCT574



Military : SN54AHCT574

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications



Texas

STRUMENTS

### TAPE AND REEL INFORMATION





#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AHCT574DBR	SSOP	DB	20	2000	330.0	16.4	8.2	7.5	2.5	12.0	16.0	Q1
SN74AHCT574DGVR	TVSOP	DGV	20	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AHCT574DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
SN74AHCT574NSR	SO	NS	20	2000	330.0	24.4	8.4	13.0	2.5	12.0	24.0	Q1
SN74AHCT574PWR	TSSOP	PW	20	2000	330.0	16.4	6.95	7.0	1.4	8.0	16.0	Q1
SN74AHCT574PWRG4	TSSOP	PW	20	2000	330.0	16.4	6.95	7.1	1.6	8.0	16.0	Q1



www.ti.com

# PACKAGE MATERIALS INFORMATION

9-Dec-2023



Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AHCT574DBR	SSOP	DB	20	2000	356.0	356.0	35.0
SN74AHCT574DGVR	TVSOP	DGV	20	2000	356.0	356.0	35.0
SN74AHCT574DWR	SOIC	DW	20	2000	367.0	367.0	45.0
SN74AHCT574NSR	SO	NS	20	2000	367.0	367.0	45.0
SN74AHCT574PWR	TSSOP	PW	20	2000	356.0	356.0	35.0
SN74AHCT574PWRG4	TSSOP	PW	20	2000	356.0	356.0	35.0

### TEXAS INSTRUMENTS

www.ti.com

9-Dec-2023

### TUBE



### - B - Alignment groove width

#### \*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	Τ (μm)	B (mm)
5962-9685301Q2A	FK	LCCC	20	55	506.98	12.06	2030	NA
5962-9685301QSA	W	CFP	20	25	506.98	26.16	6220	NA
SN74AHCT574N	N	PDIP	20	20	506	13.97	11230	4.32
SNJ54AHCT574FK	FK	LCCC	20	55	506.98	12.06	2030	NA
SNJ54AHCT574W	W	CFP	20	25	506.98	26.16	6220	NA

# **DB0020A**



# **PACKAGE OUTLINE**

SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-150.



# DB0020A

# **EXAMPLE BOARD LAYOUT**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DB0020A

# **EXAMPLE STENCIL DESIGN**

## SSOP - 2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



### MECHANICAL DATA

### PLASTIC SMALL-OUTLINE PACKAGE

#### 0,51 0,35 ⊕0,25⊛ 1,27 8 14 0,15 NOM 5,60 8,20 5,00 7,40 $\bigcirc$ Gage Plane ₽ 0,25 7 1 1,05 0,55 0°-10° Δ 0,15 0,05 Seating Plane — 2,00 MAX 0,10PINS \*\* 14 16 20 24 DIM 10,50 10,50 12,90 15,30 A MAX A MIN 9,90 9,90 12,30 14,70 4040062/C 03/03

NOTES: A. All linear dimensions are in millimeters.

NS (R-PDSO-G\*\*)

**14-PINS SHOWN** 

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15.



J (R-GDIP-T\*\*) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

## **MECHANICAL DATA**

PLASTIC SMALL-OUTLINE

MPDS006C - FEBRUARY 1996 - REVISED AUGUST 2000

### DGV (R-PDSO-G\*\*)

24 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

- C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
- D. Falls within JEDEC: 24/48 Pins MO-153

14/16/20/56 Pins – MO-194



## N (R-PDIP-T\*\*)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- $\triangle$  The 20 pin end lead shoulder width is a vendor option, either half or full width.



# **DW0020A**



# **PACKAGE OUTLINE**

### SOIC - 2.65 mm max height

SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



# DW0020A

# **EXAMPLE BOARD LAYOUT**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# DW0020A

# **EXAMPLE STENCIL DESIGN**

## SOIC - 2.65 mm max height

SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



W (R-GDFP-F20)

CERAMIC DUAL FLATPACK



- NOTES: A. All linear dimensions are in inches (millimeters).
  - This drawing is subject to change without notice. В.
  - C. This package can be hermetically sealed with a ceramic lid using glass frit.
    D. Index point is provided on cap for terminal identification only.
    E. Falls within Mil-Std 1835 GDFP2-F20



# **PW0020A**



# **PACKAGE OUTLINE**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M. 2. This drawing is subject to change without notice. 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.25 mm per side.
- 5. Reference JEDEC registration MO-153.



# PW0020A

# **EXAMPLE BOARD LAYOUT**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



# PW0020A

# **EXAMPLE STENCIL DESIGN**

## TSSOP - 1.2 mm max height

SMALL OUTLINE PACKAGE



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



# FK 20

### 8.89 x 8.89, 1.27 mm pitch

# **GENERIC PACKAGE VIEW**

## LCCC - 2.03 mm max height

LEADLESS CERAMIC CHIP CARRIER

This image is a representation of the package family, actual package may vary. Refer to the product data sheet for package details.





### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATA SHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, regulatory or other requirements.

These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

TI objects to and rejects any additional or different terms you may have proposed.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2024, Texas Instruments Incorporated